

2MBI150VA-120-50

IGBT Modules

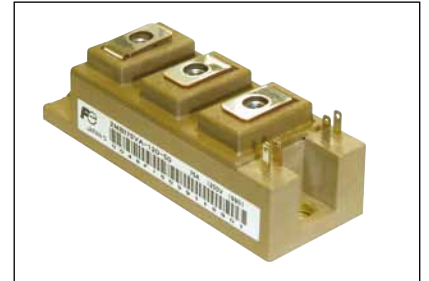
IGBT MODULE (V series) 1200V / 150A / 2 in one package

■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units
Collector-Emitter voltage	V _{CEs}		1200	V
Gate-Emitter voltage	V _{GES}		±20	V
Collector current	I _c	Continuous T _c =100°C	150	A
	I _{c pulse}	1ms	300	
	-I _c		150	
	-I _{c pulse}	1ms	300	
Collector power dissipation	P _c	1 device	785	W
Junction temperature	T _j		175	°C
Operating junction temperature (under switching conditions)	T _{jop}		150	
Case temperature	T _c		125	
Storage temperature	T _{stg}		-40 ~ 125	
Isolation voltage	V _{iso}	AC : 1min.	2500	
Screw torque	Mounting (*2)		5.0	N m
	Terminals (*3)		5.0	

Note *1: All terminals should be connected together when isolation test will be done.

Note *2: Recommendable Value : 3.0-5.0 Nm (M5 or M6)

Note *3: Recommendable Value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at T_j= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	I _{CEs}	V _{GE} = 0V, V _{CE} = 1200V	-	-	1.0	mA	
Gate-Emitter leakage current	I _{GES}	V _{CE} = 0V, V _{GE} = ±20V	-	-	200	nA	
Gate-Emitter threshold voltage	V _{GE(th)}	V _{CE} = 20V, I _c = 150mA	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	V _{CE(sat)} (terminal)	V _{GE} = 15V I _c = 150A	T _j =25°C	-	2.05	2.50	V
			T _j =125°C	-	2.35	-	
			T _j =150°C	-	2.40	-	
	V _{CE(sat)} (chip)	V _{GE} = 15V I _c = 150A	T _j =25°C	-	1.75	2.20	
			T _j =125°C	-	2.05	-	
			T _j =150°C	-	2.10	-	
Internal gate resistance	R _{G(int)}	-	-	5	-	Ω	
Input capacitance	C _{ies}	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz	-	12.6	-	nF	
Turn-on time	t _{on}	V _{CC} = 600V L _s = 30nH	-	600	-	nsec	
	t _r	I _c = 150A	-	200	-		
	t _{r(0)}	V _{GE} = ±15V	-	50	-		
Turn-off time	t _{off}	R _G = 1.1Ω	-	600	-	nsec	
	t _r	T _j = 150°C	-	40	-		
Forward on voltage	V _F (terminal)	V _{GE} = 0V I _F = 150A	T _j =25°C	-	1.85	2.30	V
			T _j =125°C	-	2.00	-	
			T _j =150°C	-	1.95	-	
	V _F (chip)	V _{GE} = 0V I _F = 150A	T _j =25°C	-	1.70	2.15	
			T _j =125°C	-	1.85	-	
			T _j =150°C	-	1.80	-	
Reverse recovery time	t _{rr}	I _F = 150A	-	150	-	nsec	

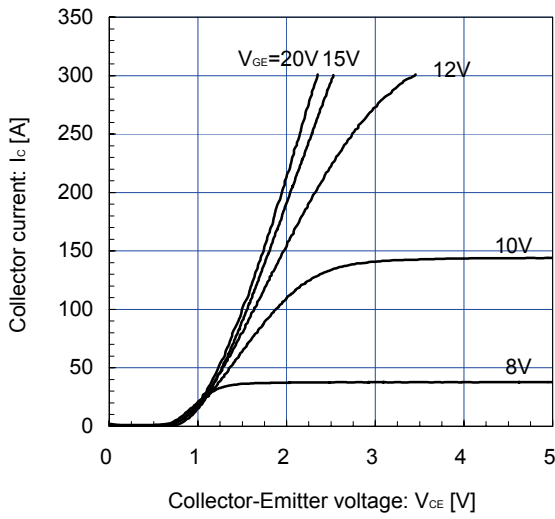
● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	R _{th(j-c)}	IGBT FWD	-	-	0.19	°C/W
Contact thermal resistance (1device) (*4)	R _{th(c-f)}	with Thermal Compound	-	0.050	-	

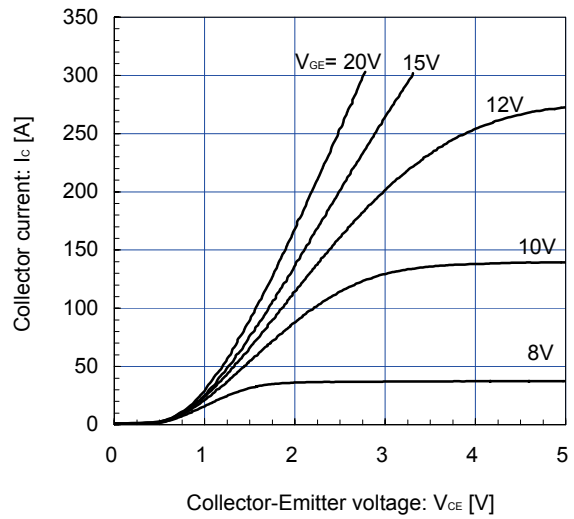
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

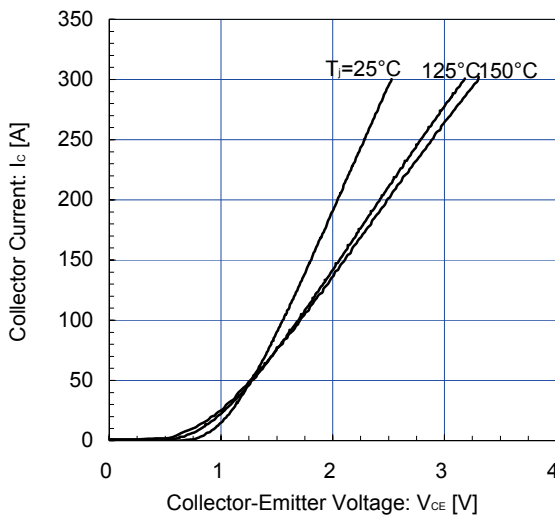
Collector current vs. Collector-Emittor voltage (typ.)
 $T_j = 25^\circ\text{C}$ / chip



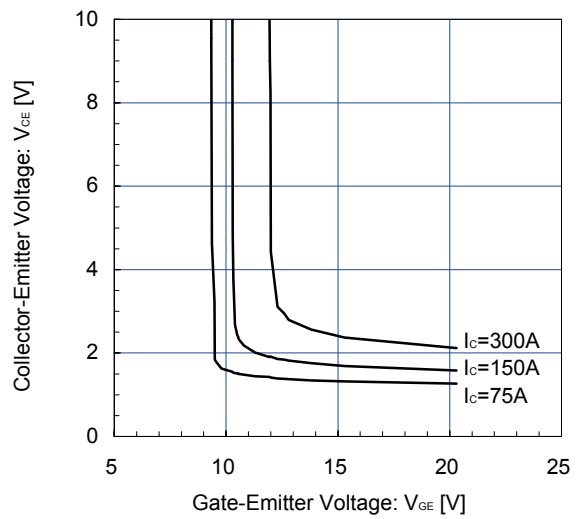
Collector current vs. Collector-Emittor voltage (typ.)
 $T_j = 150^\circ\text{C}$ / chip



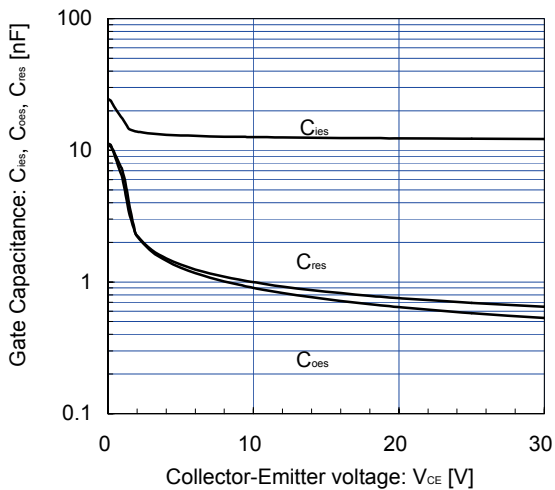
Collector current vs. Collector-Emittor voltage (typ.)
 $V_{GE} = 15\text{V}$ / chip



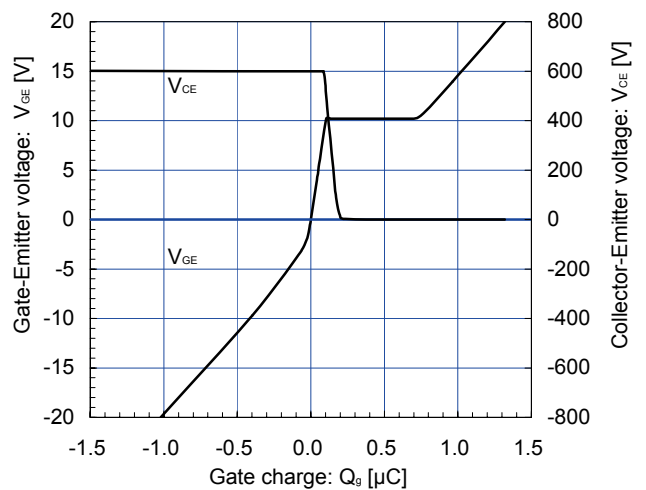
Collector-Emittor voltage vs. Gate-Emittor voltage
 $T_j = 25^\circ\text{C}$ / chip



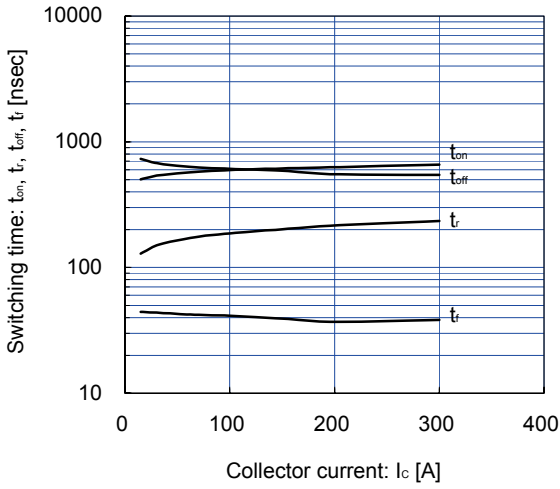
Gate Capacitance vs. Collector-Emittor Voltage
 $V_{GE} = 0\text{V}$, $f = 1\text{MHz}$, $T_j = 25^\circ\text{C}$



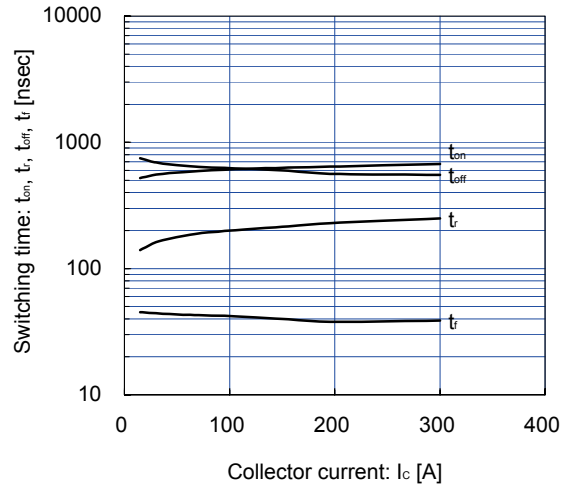
Dynamic Gate Charge (typ.)
 $V_{CC} = 600\text{V}$, $I_c = 150\text{A}$, $T_j = 25^\circ\text{C}$



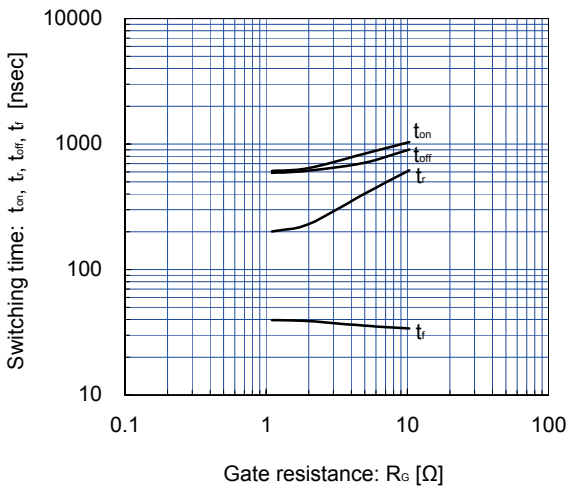
Switching time vs. Collector current (typ.)
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.1\Omega, T_J=125^\circ C$



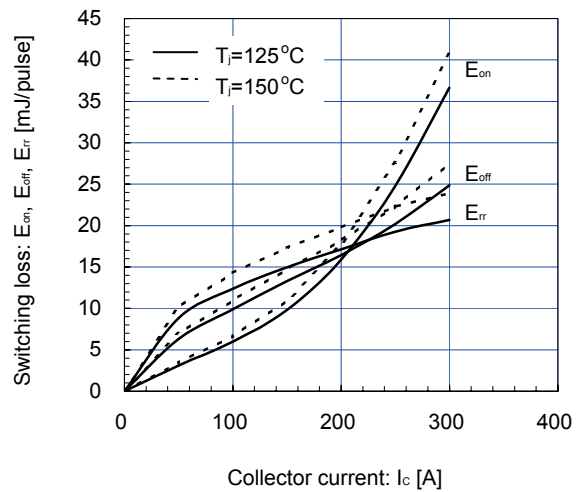
Switching time vs. Collector current (typ.)
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.1\Omega, T_J=150^\circ C$



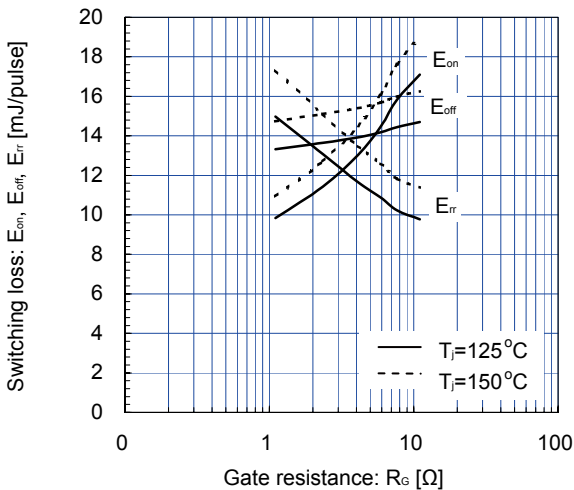
Switching time vs. Gate resistance (typ.)
 $V_{CC}=600V, I_c=150A, V_{GE}=\pm 15V, T_J=125^\circ C$



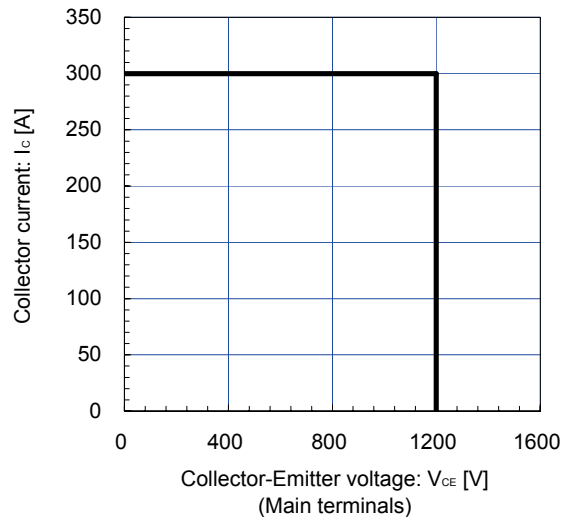
Switching loss vs. Collector current (typ.)
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=1.1\Omega, T_J=125, 150^\circ C$



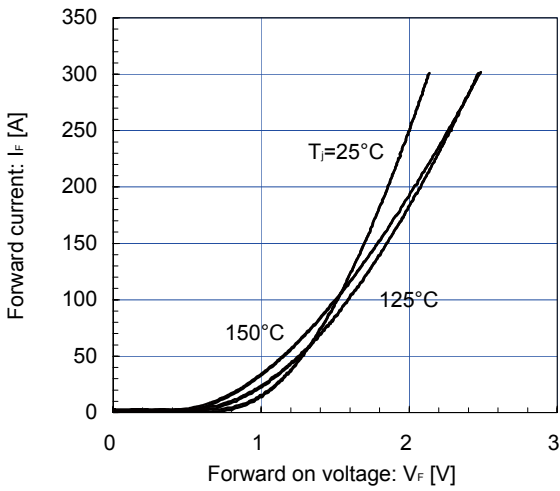
Switching loss vs. Gate resistance (typ.)
 $V_{CC}=600V, I_c=150A, V_{GE}=\pm 15V, T_J=125, 150^\circ C$



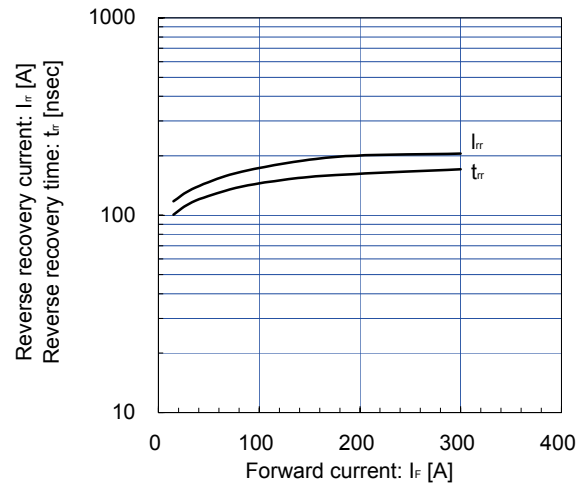
Reverse bias safe operating area (max.)
 $+V_{GE}=15V, -V_{GE}=15V, R_G=1.1\Omega, T_J=150^\circ C$



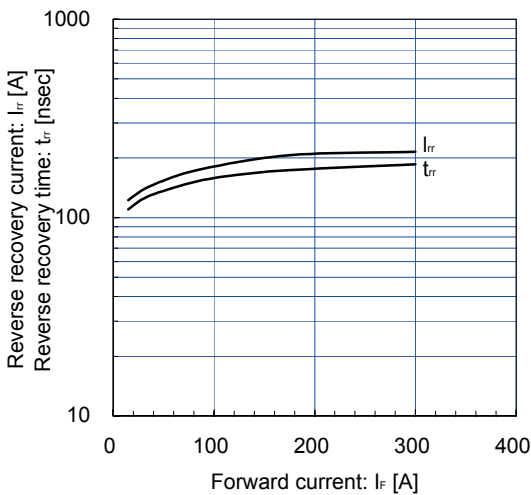
Forward Current vs. Forward Voltage (typ.)
chip



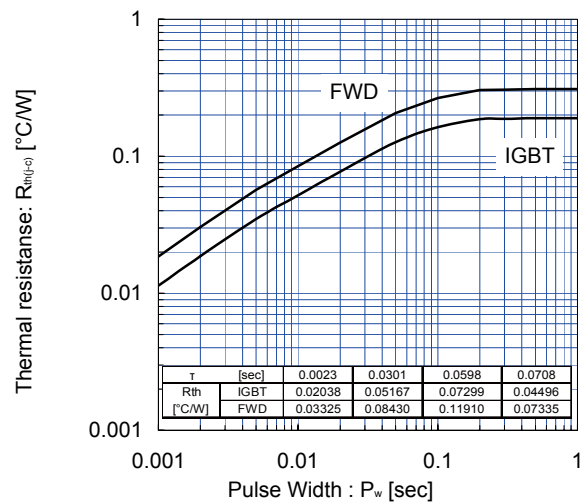
Reverse Recovery Characteristics (typ.)
 $V_{CC}=600\text{V}$, $V_{GE}=\pm 15\text{V}$, $R_G=1.1\Omega$, $T_J=125^\circ\text{C}$



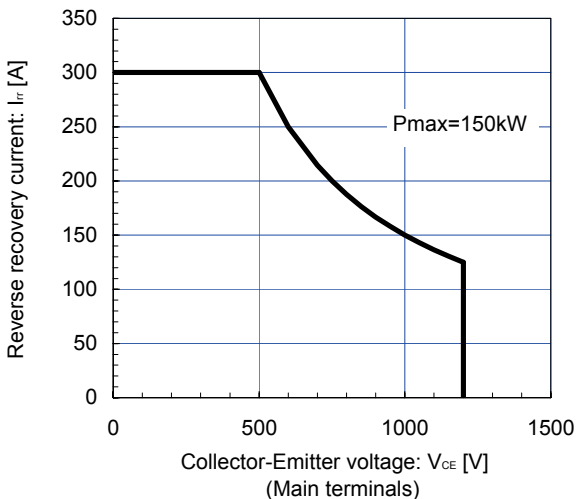
Reverse Recovery Characteristics (typ.)
 $V_{CC}=600\text{V}$, $V_{GE}=\pm 15\text{V}$, $R_G=1.1\Omega$, $T_J=150^\circ\text{C}$



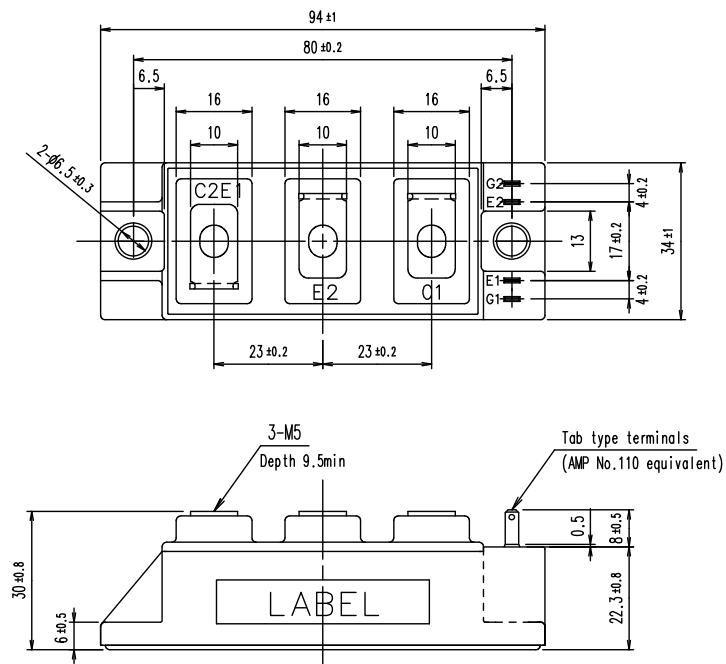
Transient Thermal Resistance (max.)



FWD safe operating area (max.)
 $T_J=150^\circ\text{C}$

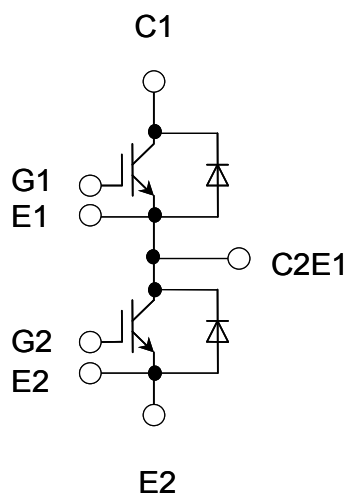


■ Outline Drawings, mm



Weight: 180g (typ.)

■ Equivalent Circuit Schematic



WARNING

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